NSN 5962-01-359-5488

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View Online at https://aerobasegroup.com/nsn/5962-01-359-5488

view Offline at https://defobasegroup.com/nsn/0302-01-009-0400
Body Width:
Between 0.442 inches and 0.460 inches
Body Height:
Between 0.060 inches and 0.100 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
W/clock and w/enable and high impedance and asynchronous and bidirectional and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
22 input
Case Outline Source And Designator:
C-4 mil-m-38510
Current Rating Per Characteristic:
15.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
And-or logic array
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
6.00 input picofarads and 12.00 output picofarads
Memory Device Type:
Pal
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 leadless
Shelf Life:
N/a
Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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